

Garcia, Joannie

From: Estrada, Michelle
Sent: Wednesday, May 29, 2002 12:16 PM
To: Garcia, Joannie
Subject: RE:

mañana ya los tienes aqui

-----Original Message-----

From: Garcia, Joannie
Sent: Wednesday, May 29, 2002 12:14 PM
To: Estrada, Michelle
Subject: RE:

Ok!! Gracias!!

Cuántos días más o menos se tardan en llegar a uno los casos?

-----Original Message-----

From: Estrada, Michelle
Sent: Wednesday, May 29, 2002 12:13 PM
To: Garcia, Joannie
Subject: RE:

te vas al email y le das "to" y escribes "warehouse" y ahí te sale.

-----Original Message-----

From: Garcia, Joannie
Sent: Wednesday, May 29, 2002 12:11 PM
To: Estrada, Michelle
Subject: RE:

Y cuál es el e-mail de Warehouse Central?

-----Original Message-----

From: Estrada, Michelle
Sent: Wednesday, May 29, 2002 12:11 PM
To: Garcia, Joannie
Subject: RE:

mandas un email a Warehouse Central pides los casos que sean y tienes que poner al final tu nombre, #empleado, #edificio y oficina y art unit.

-----Original Message-----

From: Garcia, Joannie
Sent: Wednesday, May 29, 2002 12:07 PM
To: Estrada, Michelle
Subject:

Mira??!

Cómo uno ordena casos de "2FC1"?

Day : Wednesday

Date: 5/29/2002

Time: 11:36:20

PALM INTRANET

Docket	Reg. New	Reg. Amended	Spl. New	Spl. Amended	Rejected	Counted Not
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Regular New Cases

(WARNING: Data Security and Confidentiality Restriction Apply)

Name : **GARCIA,
JOANNIE**Examiner Number : **76803**Group Art Unit : **2823**

Regular New Cases : 13

Oldest New S.N. : 09728684Oldest Effective S.N. : 09990715

Age: 01

Age: 04

No.	Appln #	Filing Date	Status	Loc	Chg To Loc	Class	Subclass	Title
1	<u>09/725853</u>	11/30/2000	30	28C1	-	438	462.000	PHOTOMASK INCLUDING AUXILIARY MARK AREA, SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF
2	<u>09/726054</u>	11/30/2000	30	28C1	-	438	128.000	METHOD OF FABRICATING SEMICONDUCTOR DEVICE
3	<u>09/728684</u>	11/30/2000	30	28C1	-	438	687.000	METHOD OF REDUCING ELECTROMIGRATION IN COPPER LINES BY CALCIUM-DOPING COPPER SURFACES IN A CHEMICAL SOLUTION AND SEMICONDUCTOR DEVICE THEREBY FORMED
4	<u>09/757514</u>	01/10/2001	30	2FC1	-	438	270.000	VERTICAL MOSFET
5	<u>09/764834</u>	01/17/2001	30	2FC1	-	438	243.000	PRODUCTION OF METAL INSULATOR METAL (MIM) STRUCTURES USING ANODIZING PROCESS
6	<u>09/766013</u>	01/18/2001	30	2FC1	-	438	192.000	6F2 TRENCH EDAM CELL WITH DOUBLE-GATED VERTICAL MOSFET AND SELF-ALIGNED STI
7	<u>09/764333</u>	01/19/2001	30	2FC1	-	438	257.000	METHOD FOR MAKING AN EMBEDDED MEMORY MOS
8	<u>09/764334</u>	01/19/2001	30	2FC1	-	438	258.000	METHOD FOR MAKING AN EMBEDDED MEMORY MOS
9	<u>09/767263</u>	01/23/2001	30	2FC1	-	438	255.000	METHOD FOR FABRICATING SEMICONDUCTOR CAPACITOR

10	09/775713	02/05/2001	30	2FC1	-	438	239.000	METHOD OF MANUFACTURING SEMICONDUCTOR DEVICE INCLUDING A STEP OF FORMING A SILICIDE LAYER, AND SEMICONDUCTOR DEVICE MANUFACTURED THEREBY
11	09/796213	02/28/2001	30	1680	-	438	243.000	METHOD FOR INCREASING THE CAPACITANCE IN A STORAGE TRENCH AND TRENCH CAPACITOR HAVING INCREASED CAPACITANCE
12	09/798923	03/06/2001	30	2FC1	-	438	257.000	SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME
13	10/026010	12/21/2001	30	2FC1	-	455	001.000	PORTABLE COMMUNICATION DEVICE THAT MAY PERMIT ONE WIRELESS NETWORK TO COMMUNICATE WITH ANOTHER WIRELESS NETWORKS AND METHOD THEREFOR

Docket	Reg. New	Reg. Amended	Spl. New	Spl. Amended	Rejected	Counted Not
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